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Enhancing perovskite solar cell performance through PbI $_2$ in situ passivation using a one-step process: experimental insights and simulations†

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The in situ passivation of a methylammonium lead triiodide (MAPbI₃) phase spin-coated via a one-step process was experimentally investigated to elucidate their fundamental properties. Structural analysis revealed that MAPbI₃ adopts a tetragonal crystal structure with a small excess of PbI₂ (0.03 M) segregating at grain boundaries. Optical characterization indicated a band gap of 1.53 eV, highlighting the material's potential as an effective visible light absorber. To facilitate the fabrication of efficient perovskite solar cells (PSCs), we employed a primary n-i-p planar structure (ITO/SnO₂/MAPbI₃/spiro-OMeTAD/Au) in drift-diffusion SCAPS-1D simulations using experimental data from MAPbI₃ layers containing excess PbI₂. The simulations predicted a high power conversion efficiency (PCE) of approximately 24%. We further analyzed the impact of series resistance, shunt resistance, MAPbI₃ thickness, defect density, as well as radiative and Auger recombination on photovoltaic performance, aiming to identify optimal parameters for enhanced device efficiency. Additionally, the use of ohmic contacts with AZO and IZO as the front and rear contacts, respectively, in the optimized device structure (AZO/SnO₂/MAPbI₃/spiro-OMeTAD/IZO) resulted in a PCE of 26.03%. These findings provide valuable insights for future research aimed at achieving high-efficiency bifacial MAPbI₃ perovskite solar cells. PAPER

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1. Introduction

The development of affordable, efficient, and stable solar technology has progressed rapidly in recent years to accelerate the world's energy transition. 3D hybrid PSCs have dominated the best cell efficiencies in emerging photovoltaic technology.^{1,2} Unveiling the full potential of 3D hybrid perovskites remains a key research focus. Despite the remarkable achievements of 3D hybrid perovskites, scientists are relentlessly pursuing innovative methods to optimize their performance. Moreover, the introduction of a novel synthesis technique aimed at controlling crystallization has signicantly enhanced the PCE of PSCs, achieving a ground-breaking efficiency of 26.1%.³ This milestone matches the previous record set by Korean researchers, who also attained this PCE by successfully controlling crystallization.⁴ 3D hybrid PSCs have achieved these high performances because of their attractive physical properties, such as high absorption coefficient, tuneable band gap via halide substitution, easy photo-generation of free charges, long carrier diffusion length, low trap density, low non-radiative recombination rate,⁵ and good mechanical proprieties, which make them suitable for flexible solar cells.^{6,7} Additionally, a simple synthesis process at low temperatures (150–200 °C of thermal annealing) is suitable for a low-cost fabrication. $8-10$ Despite all these advantages and higher PCE, 3D PSCs still

suffer from stability issues due to their morphology. The perovskite thin layer is mostly polycrystalline and comprises many small crystalline grains with numerous grain boundaries (GBs).¹¹ However, GBs attract moisture and oxygen.12,13 These defects disrupt the ordered crystalline structure and can act as recombination for photo-generated charge carriers, providing pathways for electrons and holes to recombine before being extracted from the device.¹⁴

Moreover, the presence of impurities in GBs introduces electronic trap states within the band gap of the perovskite layer. These trap states can hinder charge carriers from reaching device contacts,¹⁵ leading to the reduced performance and stability of PSCs.^{16,17} Several approaches have been developed to reduce the density of defects and traps.¹⁸–²⁰ The control of the crystallization process and film morphology can potentially minimize these defects, thereby improving efficiency and stability.²¹ This control is achieved through incorporation of a small excess of PbI_2 , which serves as an effective route for passivation.²² The excess PbI_2 preferentially segregates to grain boundaries and surfaces, resulting in the passivation of the 3D perovskite layer by suppressing interfacial recombination and reducing ionic defects, which leads to the improvement of performance.²³ Hence, the 3D perovskite structure is formed on three different components with a general formula $\text{ABX}_3,^{24}$ where A is an organic/inorganic cation, such as formamidinium iodide (FAI), methylammonium iodide (MAI), or cesium (Cs); B is a metal cation (typically Pb^{2+}); and X is a halide anion (*i.e.*, Cl^-, Br^-, I^-). MAPbI₃ is predominantly favored for use in PSCs due to its easier synthesis compared to FAPbI₃. The majority of PSCs are prepared using wet synthesis methods,^{25,26} which offer two approaches: one-step and two-step methods.²⁷ However, the one-step method is more commonly employed due to its RSC Advances Somewhole that the consent of the interaction of the strained on 1/24/2024. The consention of the strained interaction of the strained under the strained under the strained under the strained under the strain

simplicity and practicality in device fabrication. This study examines the PbI₂ in situ passivation on the MAPbI₃ perovskite films at room temperature and under ambient conditions. Passivation is performed during the process of deposition of $MAPbI₃$ thin layer by applying the one-step method, which involves spin-coating at different speeds. Moreover, we proceed experimentally to analyse the $MAPbI₃$ physical properties to achieve the optimal solar cell design. These physical properties are used in simulations using a Solar Cell Capacitance Simulator SCAPS-1D version 3.3.10.²⁸⁻³² In this study, based on the experimental results of our samples used to extract the photovoltaic parameters of the PSC device, we initially design and then simulate a one-dimensional planar PSC of n-i-p type ITO/ SnO2/MAPbI3/spiro-OMeTAD/Au.

Fig. 1(b) depicts the energy band diagram of the simulated device. The efficiency of charge transfer, which is vital for the performance of solar cells, depends on the meticulous alignment of energy levels between the perovskite absorber and the interface layers.³³ The Electron Transport Layer (ETL) must have a Conduction Band (CB) level that is lower than that of the perovskite (PVK). This difference in the CB, known as the Conduction Band Offset (CBO), facilitates the easy transfer of photo-generated electrons from the PVK to the ETL, and simultaneously, the Fermi level of the ETL must align with or be slightly lower than the Fermi level of the PVK to ensure smooth electron flow without creating an energy barrier. This is because the electrons are thermodynamically inclined to move towards the ETL's lower energy levels.³⁴ Conversely, the Valence Band (VB) of the HTL should be higher than that of the PVK, with the Fermi levels of the HTL and PVK aligned to promote effective hole transfer. This Valence Band Offset (VBO) enables the effective extraction of holes from the PVK into the HTL, as the

Fig. 1 (a) Schematic of a n-i-p structure for the PSC used in SCAPS simulations: ITO/SnO₂/MAPbI₃/spiro-OMeTAD/Au; (b) energy band diagram for the device. Inset: an energy level diagram of different materials used in the PSC with the values of BC and BV of the ETL and HTL of the selected materials.

holes are driven towards the higher energy vacant states in the HTL's VB. The CBO at SnO_2/PVK is lower (-0.07 eV), and an energy cliff is formed at the $SnO₂/PVK$ interface. This modest energy cliff does not hinder electron movement toward the ETL. In other words, no barrier is formed, allowing electrons to flow effortlessly from the absorber to the ETL due to their natural tendency to move towards lower energy states.^{34,35} Electrons tend to be transferred from $MAPbI₃$ to $SnO₂$ and then to the ITO layer to be collected, while holes are repulsed from this side. However, the VBO at the PVK/spiro-OMeTAD interface exhibits a positive value (0.36 eV). In this case, a spike is formed at this interface, which acts as a barrier to electrons. Due to this energy barrier created by the positive VBO, holes tend to migrate from the lower energy PVK layer to the higher energy HTL layer, facilitating efficient hole injection and transport.³⁶ Additionally, both electrodes should facilitate better charge transfer from adjacent layers, and their work functions should match the energy levels of adjacent layers.^{35,37,38} This strategic engineering of energy level alignments guarantees a selective extraction and transport of charge carriers and, ultimately, increases the collection of loads and, therefore, the performance of solar cells.³⁹ Puper

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2. Experimental and numerical simulation section

2.1 Experimental section about $MAPbI₃$ film synthesis

The in situ passivation is achieved using directly a small excess of PbI_2 in the primary MAPbI₃ precursor solution by a mixing ratio of 1:0.03 M of the initial MAI: PbI_2 within 2.873 ml N,Ndimethyl formamide (DMF) under atmosphere conditions, and annealing at 100 °C for a short time was required for the crystallization of $MAPbI₃$. This method promotes in situ passivation without the need for additional post-deposition PbI_2 treatments, as the excess PbI₂ segregates to the grain boundaries and surfaces, passivating defects directly during the film formation. Grazing incidence X-ray diffraction (GIXRD) measurements were carried out using a Philips X' Pert diffractometer with Cu Ka radiation ($\lambda = 1.5418$ Å) for an *ex situ* measurement of this sample from 10° to 60° at room temperature. UV-visible absorption spectra were recorded using a Shimadzu UV-3101PC UV-vis-NIR spectrophotometer. A profilometer ALTI-SURF 500 was used to measure the thickness of the layer deposited on the substrate. However, Fig. S1† summarizes the synthesis process of $MAPbI₃$ and $PbI₂$ segregation on it.

2.2 Numerical section

Solar Cell Capacitance Simulator SCAPS-1D allows us to study the influence of perovskite and other solar cell layer thicknesses under different conditions (ideal and non-ideal) on photovoltaic parameters. Moreover, it permits us to investigate the device performance with respect to several input parameters, such as relative permittivity, band gap, and bulk charge carrier density of ETL, HTL, and parasitic resistances. The simulation here is based on a classical drift-diffusion model, which solves

the electron (1) and hole (2) continuity equations and Poisson's eqn (3):

$$
\frac{\partial}{\partial x}\left(-\varepsilon(x)\frac{\partial V}{\partial x}\right) =
$$
\n
$$
q[p(x) - n(x) + N_D^+(x) - N_A^-(x) + p_t(x) - n_t(x)], \qquad (1)
$$

$$
\frac{\partial n}{\partial t} = \frac{1}{q} \frac{\partial J_n}{\partial x} + G_n - R_n, \tag{2}
$$

$$
\frac{\partial p}{\partial t} = -\frac{1}{q} \frac{\partial J_{\rm p}}{\partial x} + G_{\rm p} - R_{\rm p},\tag{3}
$$

where ε , V, q, p(x), $n(x)$, $N_D^+(x)$, $N_A^-(x)$, p_t(x), and $n_t(x)$ are the dielectric permittivity, electric potential, electronic charge, free hole density, free electron density, donor density, acceptor density, trap density of holes, and trap density of electrons, respectively.

The simulations conducted are used as input experimental optical characteristics, such as the band gap and the thickness of the MAPbI₃ absorber. A systematic investigation and optimization of the absorber thickness, defect density, series resistance (R_S) , shunt resistance (R_{Sh}) , radiative recombination coefficient, Auger electron capture coefficient, interfacial defects densities, and the impact of the front and rear contact on the overall performance of the PSC device are conducted. The simulations are carried out at 300 K under one sun irradiation with an integrated power density of 1000 W m⁻² (AM 1.5 G 1000 W cm−²). This irradiation is chosen according to standard solar cell test conditions.⁴⁴ The optical band gap of the absorber layers ($MAPbI₃$) and their thickness is obtained from experimental transmittance and UV measurements. Other parameters of the active layer, HTL, and ETL, such as thicknesses, band gap, electron affinity, permittivity, the effective density of states, charge mobility, thermal velocity, doping density, and defect density, are extracted from the literature.^{41-43,45} The ETL and HTL absorption curves are generated by SCAPS software, which are calculated using eqn (3), where $A_\alpha = 10^5$. All the input parameters used in the simulations are listed in Table 1.

3. Results and discussion

3.1 Structural and optical properties

GIXRD is particularly beneficial for analyzing thin films because it is sensitive to surface layers and detects crystal planes parallel to the substrate. In Fig. 2, the GIXRD pattern of excess $PbI₂$ $MAPbI₃$ film is compared to pristine MAPbI₃ film, as reported by Belaidi et al.⁴⁰ The structural behavior of the excess PbI_2 film closely resembles that of the pristine perovskite film, showing intense diffraction peaks at 14.00° and 28.27°, corresponding to the (110) and (220) crystal planes of the tetragonal perovskite structure,⁴⁶ with lattice parameters $a = 8.912$ Å and $c = 12.604$ Å.⁴⁷ Peaks at 12.60°, 37.83°, and 52.32°, attributed to the (001), (003), and (004) planes, respectively, indicate the presence of excess $PbI₂$.⁴⁸ The reduced intensity of the $PbI₂$ peaks in GIXRD measurements may result from the geometry of the technique, which primarily detects planes parallel to the substrate, potentially omitting PbI₂ crystals with varying orientations. This

 a^a (*) indicates the experimental value in this current work. (*) In this study, these values remain constant during initial optimization to obtain the best combination of HTL, ETL, and absorber.

Fig. 2 GIXRD pattern of the excess PbI_2 MAPbI₃ film compared to the pristine MAPbI $₅$ film.⁴⁰</sub>

could be explained by the interaction of the $MAPbI₃$ precursors (MAI and PbI₂) during annealing, where the octahedral PbI₆ units arrange themselves into a 3D tetragonal structure, with MA⁺ ions occupying the center of the framework, surrounded by eight octahedral PbI $_6$ units, resulting in MAPbI₃ adopting a tetragonal crystal structure at room temperature. Furthermore, the excess PbI_2 in the MAP bI_3 precursor solution remains unreacted and organizes itself into a 2D hexagonal lattice.^{49,50} Because the crystal structures of $PbI₂$ and $MAPbI₃$ differ significantly, direct epitaxial growth of perovskite on the $PbI₂$ (001) plane is unlikely. However, one possible explanation for the locally oriented growth of perovskite crystals could be 'pseudo-epitaxial' nucleation, as reported by Brenner et al .⁵¹ In this scenario, the tetragonal perovskite (202) plane, which closely resembles the PbI_2 (001) plane in bonding and lattice parameters, may serve as the nucleation site. With this alignment, subsequent crystal growth occurs at an approximate 45° angle along the perovskite (002) plane, allowing the structure to accommodate the differing lattice parameters of $PbI₂$ and

 $MAPbI₃$. This segregation pattern can be rationalized by noting that if $PbI₂$ was located within the perovskite grains instead of at the grain boundaries, it induces a change in the lattice parameters. However, the literature findings commonly report the lattice parameters of MAPbI₃ as $a = 8.912 \text{ Å}$ and $c = 12.604$ Å.^{52,53} This observation supports the conclusion that $PbI₂$ segregation predominantly occurs at the grain boundaries rather than within the perovskite grains. Consequently, the observed passivation effect may arise from band bending at the interface between the perovskite and $PbI₂$, as suggested in the work by Chen et al.⁵⁴ The obtained results show crystallites with an average size of 179.8 nm. These grain sizes are in the range observed in high-performance MAPbI₃ solar cells, which should be greater than 100 nm.¹¹ This means that the spin conditions chosen for depositing $MAPbI₃$ are suitable for obtaining a highquality MAPbI₃ layer.

Furthermore, the recent report of Zhang et al. findings⁵⁵ also confirmed that the slightly excess PbI_2 (1.05 M) perovskite film, which is marginally closer to our chosen excess $PbI₂$ (1.03 M) perovskite composition, demonstrates a similar tendency to our results. Interestingly, their results also demonstrated that the excess PbI_2 (1.05 M) perovskite device displayed an enhanced power conversion efficiency (16.5%) compared to the pristine solar cell (14.3%). In general, the excessive $PbI₂$ introduces extra I-into the $MAPbI₃$ perovskite, which significantly alters the halide vacancies and reduces the defect-induced nonradiative recombination.55,56

To investigate the thickness of the sample, a Profilometer ALTISURF 500 was used. The measured thickness is above 2.02 \pm 0.005 µm, and this thickness is used in the next part. The absorption spectrum is shown in Fig. 3(a). The absorption spectrum of the MAPbI₃ film on glass, measured from 300 nm to 860 nm, demonstrates a broad absorption range that encompasses both visible and near-infrared wavelengths. Notably, there is an increase in absorption at shorter wavelengths (around 810 nm), with an absorption coefficient (α) of approximately 5 \times 10³ cm⁻¹. The deposited layer appears almost black (grey-dark), which indicates good absorption. This observation is consistent with the known optical properties of

perovskite materials, where a darker color generally corresponds to higher light absorption due to increased optical density and effective bandgap utilization.57,58 Additionally, excessive PbI₂ treatment is found to passivate grain boundaries and suppress the formation of trap states in the perovskite material, enhancing charge carrier movement and decreasing recombination, which enhances absorption.⁵⁹

Furthermore, from the transmittance spectra (see Fig. 3(a)), and based on the Beer–Lambert law defined using eqn (4) , we estimate the band gap of the film, whereas the absorption curve is calculated as follows:

$$
T = e^{-\alpha d} \tag{4}
$$

Moreover, the bandgap $E_{\rm g}$ was estimated using the Tauc relation as follows:

$$
\alpha h\nu = A[h\nu - E_{\rm g}]^n, \tag{5}
$$

where d is the thickness of MAPbI₃ layers (2.02 μ m extracted experimentally), A is a constant, and the parameter n was taken as equal to 1/2 for the direct band gap. The estimated band gap of 1.53 eV (Fig. 3(b)) is useful for simulations in the next subsection. Furthermore, Makuła et al.⁶⁰ suggested a method for accurately determining the band gap energy based on UV-vis spectra. As shown in Fig. S2,† we found almost the same band gap energy using this method as we did when employing the classical method.

3.2 Theoretical analysis of device performance

The J–V characteristics obtained from the simulations of the primary device (ITO/SnO₂/MAPbI₃/spiro-OMeTAD/Au) carried out using photovoltaic parameters, such as open circuit voltage (V_{OC}) , short circuit current (J_{SC}) , fill factor (FF) and PCE, are shown in Fig. 4, where $V_{\rm OC}$ = 1.00 V, $J_{\rm SC}$ = 35.04 mA cm $^{-2}$, FF = 68.01%, and PCE $= 23.93\%$. These promising results can be attributed to the enhancement of the perovskite/HTL interface, indicating that an excess of $PbI₂$ improves device performance and leads to higher photovoltaic efficiency. The incorporation of a small excess of PbI_2 serves as an effective pathway for passivation, as reported in the literature.^{48,61-63} When carefully managed, excess PbI₂ helps maintain a balance between crystallinity and the suppression of interfacial recombination, as it preferentially segregates at grain boundaries and surfaces, thereby improving performance.²³ Promising results can be attributed to the enhancement of.⁵⁹ Moreover, the performance of solar cells relies on aligning the energy levels, which are crucial for efficient charge transfer between the perovskite absorber and interface layers.³³ In summary, the chosen material layers in this cell exhibit suitable energy alignment conditions. Consequently, this work proposes a simple in situ passivation using a one-step method in the device design of ITO/SnO2/MAPbI3/spiro-OMeTAD/Au, achieving a PCE above 24%. This highlights the role of excess $PbI₂$ in enhancing PSC performance, with these photovoltaic parameters being

Fig. 4 $J-V$ characteristics of the MAPbI₃-based solar cell using the photovoltaic parameters obtained from simulation.

encouraging compared to published reports in the literature.^{13,48,59}

3.2.1 Impact of the series and shunt resistance on photovoltaic performances. For high-efficiency devices, series resistance $(R_{\rm S})$ should not exceed 1 Ω cm², and the shunt resistance $(R_{\rm sh})$ should be greater than 10⁷ Ω cm².⁶⁴ $R_{\rm S}$ originates from the impedance of electrodes, including the front and the back contacts (ITO and Au). However, the R_{sh} effect arises from manufacturing defects. Therefore, to understand the impact of parasitic resistances $(R_S$ and R_{Sh}) on the efficiency of the PSC, which converts solar cell power into electrical energy, we incorporate them into the SCAPS-1D model. Fig. 6a–d depicts the contour mapping of the R_S and R_{Sh} resistances and their effect on the PSC performance. R_S and R_{sh} are varied from 0 to 8 Ω cm 2 and 10 to 10 8 Ω cm 2 , respectively. $R_{\rm S}$ and $R_{\rm sh}$ regulate the J–V characteristics, which have a signicant effect on the device performance. R_S includes different resistances, such as the resistance due to metal contact, and resistance at the interface between layers, and each bulk layer has its resistance. $R_{\rm sh}$ is influenced by the device architecture. This is due to the variation in the charge recombination process, including the leakage current across cell edges.⁶⁵ Fig. 5a–d illustrates that all the PSC performances exhibit dropping-downs, with an increase in R_S . Fig. 5(a) shows that V_{OC} is negligible and independent from R_S . The J_{SC} of the PSC decreases slowly from 35.04 to 34.88 mA cm−² , as presented in Fig. 5(b), while the FF is observed to be reduced from 69.70 to 43.80%, as depicted in Fig. 5(c). Fig. 5(d) shows that PCE is reduced from 22.98% to 14.90%. An increase in R_s leads to a reduction in FF and PCE due to increased power dissipation, as initially stated above.⁶⁶ However, when $R_{\rm sh}$ is sufficiently high (above 5 \times 10⁶ Ω cm²), FF and PCE tend to improve. This improvement occurs because a high $R_{\rm sh}$ minimises leakage currents, thereby increasing the efficiency of the p–n junction and allowing more photocurrent to be collected. Although J_{SC} remains relatively constant, V_{OC} increases slowly due to reduced recombination at higher R_{sh} values, supporting better overall device performance.⁶⁷ RSC Advances Compared to published topots in the broxidional by the heights and both the comparison in the thicker computer of the same o

3.2.2 Impact of the thickness and defect density (N_t) of $MAPbI₃$ on photovoltaic performances. The optimum conditions belong to the effect of the thickness, and the density of the defects (N_t) in the absorbing layer plays a crucial role in light absorption and charge generation in PSCs. Contour maps of the projected $V_{\text{OC}}, J_{\text{SC}}$, FF, and PCE with varying absorber thickness (1 μm to 3 μm) and $N_{\rm t}$ (1 \times 10^{10} ${\rm cm^{-3}}$ to 1 \times 10^{16} ${\rm cm^{-3}})$ for the $\text{MAPbI}_3\text{-based PSCs}$ are extracted, as shown in Fig. 5(a $'$)–(d $'$). These contour maps illustrate how the photovoltaic parameters are affected by the combined change in the absorber N_t and the thickness. In Fig. 5(a′), the $V_{\rm OC}$ remains relatively constant once the thickness increases and N_t is lower than 1 × 10¹⁴ cm⁻³. As $N_{\rm t}$ is increased to values higher than 1 \times 10 14 cm $^{-3},~V_{\rm OC}$ decreases slightly from 0.990 V to 0.596 V. This means that the defect's density is mainly responsible for the observed change in V_{OC} for the conventionally structured solar cell.⁶⁸

Simultaneously, Fig. 5 (b') shows that the J_SC extended to a maximum of 44.7 mA cm⁻² when the N_t was higher than 5 \times 10^{14} cm⁻³ and an absorber thickness was higher than 3 µm. Meanwhile, the J_{SC} increases steadily with thickness. This can be explained by the heightened light absorption in the thicker absorber layer, leading to enhanced current generation.⁴³ However, an inversely proportional relationship between increasing thickness, N_t , and FF progressively decreases in thickness due to the possibility of increased series resistance in thicker devices, leading to a reduction in FF. Furthermore, Fig. 5(d') shows that when the N_t was <5 × 10¹⁴ cm⁻³ and the absorber thickness was $\geq 2 \mu m$, the corresponding highest PCE value of 30.10% is achieved. The PCE initially increases with thickness and reaches its maximum PCE at a thickness of $3 \mu m$. A linear relationship between the increase in thickness and the absorption of light leads to the generation of a greater number of electron–hole pairs. This increases the photocurrent and thus improves the efficiency of energy conversion. Consequently, the presence of excess PbI₂ on the perovskite layer leads to larger photovoltaic parameters. The optimizing perovskite layer thickness and defect density N_t results in the FF decrease from 71.60% to 26.20%, as shown in Fig. 5(c'). However, the FF presents a gradual decrease with increased $1.7 \mu m$ to $3 \mu m$ (in all this range of thickness with had found high performance of PSC) and N_t less than 5 \times 10¹⁴ cm⁻³. The recombination directly affects the performances of the PSCs, and the recombination losses are due to defects in the materials.⁶⁹ Recombination losses limit the collection of the current and directly affect the current density and the voltage of the PSC.

3.2.3 Impact of the radiative and auger recombination on photovoltaic performances. The recombination directly affects the performances of the PSCs, and the recombination losses are certain due to defects in the materials.⁶⁹ Recombination losses limit the collection of the current and directly affect the current density and voltage of the PSC. To analyze the effect of the radiative and Auger recombination on the device performances, we varied the radiative recombination coefficient (B_{rad}) from 10^{-12} to 10^{-7} cm³ s⁻¹, and the Auger electron/hole recombination coefficient ($B_{\rm n/p}$), varied from 10 $^{-28}$ to 10 $^{-23}$ cm 6 s $^{-1}$, are represented as contour mapping, as shown in Fig. 6(a)–(d). The higher values of B_{rad} and $B_{n/p}$ exhibit an adversative effect on the PV performances of the device. From Fig. 6(a)–(d), we observed a higher value of PCE (22.95%), FF (67.10%), V_{OC} (0.9765 V), and $J_{\rm SC} \, (\rm 35.05\;mA\;cm^{-2})$ at a lower value $B_{\rm rad}$ of $10^{-12}\; \rm cm^3\; s^{-1}.$ The PCE of the decreased to 9.56% as $B_{\rm rad}$ increased to 10^{-7} $\rm cm^{3}$ $\rm s^{-1}.$ Otherwise, PSC exhibits higher performance at a high value of $B_{n/p}$ Auger, where we observe that the effect of $B_{n/p}$ Auger on the PSC performances is neglected compared to the effect of B_{rad} .⁶⁶ Consequently, the B_{rad} value in the range of 10^{-12} – 10^{-10} cm³ s⁻¹ is suitable for higher PV performances, and the minimum performance occurs at a higher value of 10^{-23} cm³ s⁻¹. Compared with Auger recombination, radiative recombination is the dominant mechanism in perovskite solar cells due to their direct band gap large dielectric constant, which means that photon emission is very efficient via band-to-band transitions.⁷⁰ Owing to the passivation of perovskite by excess PbI_2 , we achieved high performance even in the presence of band-toband recombination. Without passivation, the presence of band-to-band recombination results in lower performance.

3.2.4 Impact of the interfacial defect density on the photovoltaic performances. Interface defect density is a critical

Fig. 5 Contour mapping of PSC performances illustrating the effect of the variation in series and shunt resistances on the performance of the PSC by $V_{\rm OC}$ (a), $J_{\rm SC}$ (b), FF (c), and PCE (d). Contour mapping of PSC performances by $V_{\rm OC}$ (a'), $J_{\rm SC}$ (b'), FF (c'), and PCE (d') with the variation in thickness and density defects N_t of the MAPbI₃ absorber layer.

Fig. 6 Contour mapping representing the effect of the radiative recombination coefficient (cm³ s^{−1}) and Auger electron capture coefficient (cm⁶ s $^{-1}$) on the PSC performances: (a) V_{OC}, (b) J_{SC}, (c) FF and (d) PCE. The effect of interface defect density at the MAPbI₃/SnO₂ interface and spiro-OMeTAD/MAPbl₃ interface is presented in (a') V_{OC} , (b') J_{SC} , (c') FF, and (d') PCE.

parameter influencing the performance of PSCs, as it directly affects interfacial recombination. Recombination occurring at the interfaces between the absorber and transport layers results in the formation of interface defect states. In our study, we systematically varied the interface defect density from 10^{10} cm⁻² to 10¹⁵ cm⁻² at the MAPbI₃/SnO₂ and MAPbI₃/spiro-OMeTAD interfaces to assess their impact on the photovoltaic performance of PSCs, as illustrated in Fig. $6(a')$ – (d') . These figures depict the contour mapping of defect density variations at the $MAPbI_3/SnO_2$ and spiro-OMeTAD/MAPbI₃ interfaces, revealing that the highest PSC performances are achieved when the $N_{\rm t}$ ranges from 10^{10} to 10^{14} cm^{−2}. Beyond this range (>10¹⁴ $\rm cm^{-2})$, there is a slight decrease in PCE, $J_{\rm SC}$, and $V_{\rm OC}$, indicating suboptimal conditions. Specifically, the significant decrease in performance is attributed to higher recombination rates at the $MAPbI₃/spiro-OMeTAD$ interface. These findings underscore the critical importance of optimizing interface defect densities within the specified range to enhance the overall efficiency and stability of PSCs. Future research efforts should focus on further refining these interfaces to achieve even higher performance levels.71,72

3.2.5 Impact of the work function of front and back contact on photovoltaic performances. There are several studies in which the back metal work function (WF) has been varied to obtain better performance, but there are limited studies about the effect of WF on front contact. Herein, we reported the impact of WF on recent contacts (front and rear), such as aluminium-doped ZnO (AZO) ,⁷³ nanowire of silver with the introduction of gold and molybdenum oxides (AgNW–Au– MoO3) ⁷⁴ and hydrogen-doped indium oxide deposited on ITO (IOH/ITO);⁷⁵ additionally, we reported the rear contacts, such as Au, nanowire of silver (NWs Ag), single-walled carbon nanotubes (SWCNTs),^{76,77} and indium zinc oxide In_2O_3 :Zn (IZO), the last one being recently used as a rear contact for semitransparent solar cells.78,79 The work functions of these

Fig. 7 Effect of the work function of different contacts (back and front contacts) on the power conversion efficiency of planar perovskite solar cells, MAPbI $_3$ as a perovskite absorber, SnO₂ as ETM and spiro-OMeTAD as HTL.

materials are extracted from the literature. Fig. 7 demonstrates that the WF of the back and front contacts varies from 4.3 eV to 5.4 eV and from 4.1 to 4.7 eV to illustrate the impact of the WF of both contacts on the performance of PSC. The PCE of our simulated solar cell with varying back and front contacts is shown in Fig. 7. The increasing work function of back contact increases the PSC performance, where the maximum PCE in its case is above 5.3 eV. This could be attributed to the MAPbI₃ work function (−5.46 eV), which saturates the efficiency, due to the alignment of the HTL work function and the valence band of the absorber layer. Using a high metal work function, the Fermi level energy decreases due to the band bending at the metalsemiconductor interface, making the contact more ohmic and the type of contact we attempt to achieve in PSC.⁸⁰ We assume that IZO could be used as a transparent back contact. Otherwise, in the front contact (see Fig. 7), the PCE decreases with the work function. This could be explained as follows: a front contact with a high work function leads to an increase in the interface recombination as an energy barrier prevents electron transfer into the front contact, and the occurrence of inverted band bending, which hinders charge transport and collection.⁸¹ To aim to achieve optimal PSC performance, it is crucial to carefully choose a front contact with a work function slightly higher than the conduction band of absorber layer $MAPbI₃$ (∼4.0 eV). In this case, the AZO is the best front contact for the PSC. Paper

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After using all the optimization values obtained previously, we hypothesize that the IZO and AZO with work functions of 5.3 eV and 4.19 eV, respectively, could be chosen as an effective alternative to replace the Au and ITO, respectively. An encouraging performance of PSC using these contacts is achieved by applying this structure $A ZO/SnO₂/MAPbI₃$ with excess $PbI₂/$ spiro-OMeTAD/IZO, giving $V_{\text{OC}} = 1.08 \text{ V}, J_{\text{SC}} = 36.90 \text{ mA cm}^{-2}$, $FF = 65.16\%$ and $PCE = 26.03\%$. The introduction of IZO on PSC is reported for the first time by Wahl et al.,⁸² where they demonstrated efficient inverted semi-transparent perovskite solar cells by implementing a sputtered IZO layer as TCO on organic electron transport layers without using a protective buffer layer with a PCE of around 13%. It could be improved with the introduction of a front metal contact with a low work function as demonstrated by our results.

Fig. 8 illustrates the photovoltaic performance of the MAPbI3-based perovskite solar cell, highlighting all key parameters. Our study demonstrates that incorporating a small excess of PbI₂ during the fabrication process leads to the formation of a passivation layer on the perovskite surface. This layer acts as a barrier, preventing ion migration, which is a common cause of performance degradation and instability in perovskite solar cells. The simulation results based on this simple synthesis method are promising, with an optimized device structure $(AZO/SnO₂/MAPbI₃$ with excess PbI₂/spiro-OMeTAD/IZO) achieving a PCE of 26%. Even prior to optimization, the initial device $(ITO/SnO₂/MAPbI₃/spiro-OMeTAD/Au)$ shows a competitive PCE of 24%. These values are comparable to devices reported in the literature that use excess $PbI₂$ for passivation, yet our method simplifies the process and maintains high performance.

Fig. 8 J–V characteristics of the old and new architecture of the MAPbI3-based solar cell with the photovoltaic parameters, and the inset shows a schematic of design of the n-i-p structure for the PSC used in SCAPS simulation: AZO/SnO₂/MAPbI₃ with excess PbI₂/spiro-OMeTAD/IZO.

Table 2 summarizes the PV performance comparison of published experimental and theoretical works with the current work, explicitly using excess PbI₂ with AZO and IZO as front and rear contacts, respectively. The experimental and theoretical studies by Chen et al.⁴⁸ showed that PSCs with an in situ passivation using an excess PbI_2 device structure $(ITO/SnO_2/$ $(FAPbI₃)_{x−1}(MAPbBr₃)_x/spiro-OMeTAD/Au)$ offer a PCE of ~19% even when they used perovskite material more stable than $MAPbI₃$.

Similarly, Duan et al.⁵⁹ experimentally proved that the PSCs $(ITO/SnO₂/MAPbI₃/spiro-OMETAD/Ag)$ provide a good efficiency of 21.23%. The perovskite films were prepared by two-step

sequential deposition, excess PbI_2 was distributed on the surface of the perovskite film, and then a dual-functional surfactant (oleamide) was introduced to control the distribution of excess PbI_2 on the perovskite films. Even with the high PCE achieved by this device, the procedure of elaborating the $MAPbI₃$ is complex and expensive because of the chemical compounds used. Furthermore, Runnan Yu et al.¹³ proved that the $PbI₂$ excess enhances the photovoltaic performance, achieving a PCE of 23.22% for $(ITO/SnO₂/FA_{0.92}MA_{0.08}PbI₃/)$ $PEAI/HTL/Moo₃/Ag)$ using a one-step process incorporated into PbI₂ an oxime acid-based material with multi-coordination sites and ethyl 2-(2-aminothiazole-4-yl)-2-hydroxyiminoacetate (EHA). Their results show that the choice of the one-step deposition process is effective and leads to good photovoltaic parameters. In a very recent development, Jiang et al.⁸³ employed IZO as a rear electrode and (2-(9H-carbazol-9-yl)ethyl) phosphonic acid (2PACz) to the passivation of the interface between the HTL and perovskite, which provided better stability with a higher PCE of 20.01%. Moreover, Wang et al.⁸⁴ proposed a method to improve the performance of PSCs by texturing the surface of the underlying AZO substrate, ultimately leading to a higher PCE of 17.6% for this textured device $(AZO/SnO₂/$ MAPbI3/spiro-OMeTAD/Ag). Without using any passivation of the perovskite/HTL interface. Dubey et al.⁷³ carried out experimental and simulation work of the PSC device (PET/AZO/ZnO-NRs/MASnI3:xLn3+/PTAA/Au), highlighting the promising potential of AZO as front contact and lanthanide ion doping in the absorbent layer as it has remarkably improved the photovoltaic performance of PSCs (25.85%). **PSC Advances**
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The comparison of our results with the literature highlights the positive effect of an in situ passivating interface by an excess of PbI₂ using a one-step spin-coating method rather than depositing it as a separate thin layer beneath the perovskite or employing more complex deposition techniques, such as the

Table 2 Summary of the MAPbI₃'s in situ passivation via spin-coating (one and two-step) reported in the literature

4. Conclusion

We correlated the experimental and theoretical investigations of the in situ passivation of the MAPbI₃ layer using a costeffective one-step method of deposition by spin coating. The structural and optical characteristics are investigated. The tetragonal structure of the MAP bI_3 film is confirmed to be oriented along the (110) with an average size of ∼179.8 nm. Moreover, the deposited MAPbI₃ presented a PbI₂ phase, which means there is a segregation of $PbI₂$ on the MAPbI₃ phase where it segregated at its GBs. However, the thickness of $MAPbI₃$ is above 2.02 μ m. The band gap (1.53 eV) and the absorption coefficient $(5 \times 10^3 \text{ cm}^{-1})$ of the MAPbI₃ absorber were extracted from the transmittance UV spectra, indicating a high absorption. Furthermore, the experiments are supported by theoretical calculations. The MAPbI₃-based planar PSC (i.e., $ITO/SnO₂/MAPbI₃$ with excess $PbI₂/spiro-OMeTAD/Au$ is conducted utilizing drift-diffusion SCAPS-1D simulations. The simulated PSC demonstrates a high efficiency of [∼]23.93%, surpassing other devices passivized using $PbI₂$ excess. The impact of R_S and R_{Sh} on PSC performances is deeply investigated. Results show that R_S presents a negative impact on PSC performances while the $R_{\rm Sh}$ reveals a positive impact. A study to find the optimum parameters of absorber thickness and defect density (N_t) , series and shunt resistances, radiative recombination coefficient, Auger hole/electron capture coefficient, and interfacial defect densities is carried out. In addition, the effects of changing the back and front contacts are investigated. The IZO and AZO are the most effective alternatives to replace the Au and ITO and give the highest performance. Even with the most unstable lead-halide perovskite $(MAPbI₃)$, the final PCE is optimized to be 26.03%, which is an encouraging result and turns attention to the ST-PSCs. We believe that our work could provide an alternative way to enhance experimentally the efficiency of lead-halide perovskites-based solar cells using a simple method of depositing and passivating the interface between $MAPbI₃$ and HTL, which is the main cause of decreasing the PCE of PSCs. As well, our results could help integrate perovskites on III–V class substrates such as GaAs, GaN and their derivative compounds. Paper

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Data availability

The data that support the findings of this study are available in the ESI† of this article.

Conflicts of interest

There are no conflicts to declare.

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